



High-end Power Semiconductor Manufacturer

ZP630A 2400-4000V Standard Rectifier Diode

- High power cycling capability
- Low on-state and switching losses
- Optimized for line frequency rectifiers
- Designed for traction and industrial applications



Average forward current				I_{FAV}		630 A			
Repetitive peak reverse voltage				V_{RRM}		2400 – 4000 V			
V_{RRM}, V	2400	2600	2800	3000	3200	3400	3600	3800	4000
Voltage code	24	26	28	30	32	34	36	38	40
$T_j, ^\circ C$	-60 – 150								

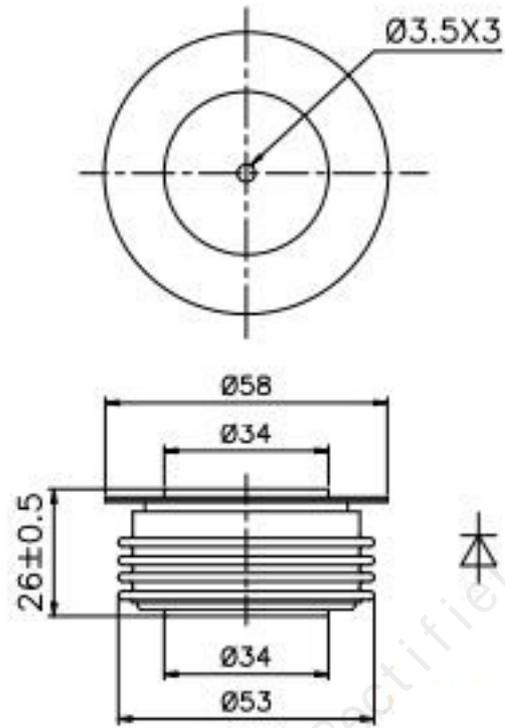
MAXIMUM ALLOWABLE RATINGS

Symbols and parameters		Units	Values	Test conditions
ON-STATE				
I_{FAV}	Average forward current	A	630	$T_c=100\text{ }^\circ C$; Double side cooled; 180° half-sine wave; 50 Hz
I_{FRMS}	RMS forward current	A	989	$T_c=112\text{ }^\circ C$; Double side cooled; 180° half-sine wave; 50 Hz
I_{FSM}	Surge forward current	kA	10.5 11.0	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 50 Hz ($t_p=10\text{ ms}$); single pulse; $V_R=0\text{ V}$;
			12.0 13.8	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 60 Hz ($t_p=8.3\text{ ms}$); single pulse; $V_R=0\text{ V}$;
I^2t	Safety factor	$A^2s \cdot 10^3$	550 730	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 50 Hz ($t_p=10\text{ ms}$); single pulse; $V_R=0\text{ V}$;
			595 790	$T_j=T_{j\max}$ $T_j=25\text{ }^\circ C$ 180° half-sine wave; 60 Hz ($t_p=8.3\text{ ms}$); single pulse; $V_R=0\text{ V}$;
BLOCKING				
V_{RRM}	Repetitive peak reverse voltages	V	2400 – 4000	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave; 50 Hz;
V_{RSM}	Non-repetitive peak reverse voltages	V	2500 – 4100	$T_{j\min} < T_j < T_{j\max}$; 180° half-sine wave; 50 Hz; single pulse;
V_R	Reverse continuous voltages	V	$0.75 \cdot V_{RRM}$	$T_j = T_{j\max}$;
THERMAL				
T_{stg}	Storage temperature	$^\circ C$	-60 – 50	
T_j	Operating junction temperature	$^\circ C$	-60 – 150	
MECHANICAL				
F	Mounting force	kN	14.0 – 16.0	
a	Acceleration	m/s^2	50	Device unclamped
			100	Device clamped

CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
ON-STATE				
V_{FM}	Peak forward voltage, max	V	2.11	$T_j=25\text{ }^\circ\text{C}; I_{FM}=1978\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	1.11	$T_j=T_{j\text{ max}}$;
r_T	Forward slope resistance, max	$m\Omega$	0.740	$0.5\pi I_{FAV} < I_T < 1.5\pi I_{FAV}$
BLOCKING				
I_{RRM}	Repetitive peak reverse current, max	mA	70	$T_j=T_{j\text{ max}}$; $V_R=V_{RRM}$
THERMAL				
R_{thjc}	Thermal resistance, junction to case, max	$^\circ\text{C/W}$	0.027	Double side cooled
R_{thjc-A}			0.060	Anode side cooled
R_{thjc-K}			0.049	Cathode side cooled
R_{thck}	Thermal resistance, case to heatsink, max	$^\circ\text{C/W}$	0.006	Direct current
MECHANICAL				
w	Weight, typ	g	260	
D_s	Surface creepage distance	mm (inch)	23.69 (0.933)	
D_a	Air strike distance	mm (inch)	19.10 (0.752)	

OVERALL DIMENSIONS



ZT40

All dimensions in millimeters